





RF TEST REPORT

Applicant Quectel Wireless Solutions Co., Ltd

FCC ID XMR201910BG95M3

Product LTE Cat M1 & Cat NB2 & EGPRS Module

Brand Quectel

Model BG95-M3

Report No. R2003A0152-R2

Issue Date May 22, 2020

TA Technology (Shanghai) Co., Ltd. tested the above equipment in accordance with the requirements in FCC CFR47 Part 2 (2019)/ FCC CFR 47 Part 24E (2019). The test results show that the equipment tested is capable of demonstrating compliance with the requirements as documented in this report.

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Summary of measurement results

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No.	Test Case	Clause in FCC rules	Verdict
1	RF power output	2.1046	PASS
2	Effective Isotropic Radiated power	24.232(c)	PASS
3	Occupied Bandwidth	2.1049	PASS
4	Band Edge Compliance	2.1051 /24.238(a)	PASS
5	Peak-to-Average Power Ratio	24.232/KDB 971168 D01(5.7)	PASS
6	Frequency Stability	2.1055 / 24.235	PASS
7	Spurious Emissions at Antenna Terminals	2.1051 / 24.238(a)	PASS
8	Radiates Spurious Emission	2.1053 / 24.238(a)	PASS

Date of Testing: August 20, 2019 ~ September 5, 2019

Note: PASS: The EUT complies with the essential requirements in the standard.

FAIL: The EUT does not comply with the essential requirements in the standard.

All indications of Pass/Fail in this report are opinions expressed by TA Technology (Shanghai) Co., Ltd. based on interpretations and/or observations of test results. Measurement Uncertainties were not taken into account and are published for informational purposes only.

There is no test for BG95-M3 in this report(Report No.:R2003A0152-R2). All test values duplicated from the BG95-M3 report (Report No.: R1907A0446-R2). The detailed product change description please refers to the *Statement letter*.



1. Test Laboratory

1.1. Notes of the test report

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(shanghai) co., Ltd. The results documented in this report apply only to the tested sample, under the

conditions and modes of operation as described herein .Measurement Uncertainties were not taken

into account and are published for informational purposes only. This report is written to support

regulatory compliance of the applicable standards stated above.

1.2. Test facility

FCC (Designation number: CN1179, Test Firm Registration Number: 446626)

TA Technology (Shanghai) Co., Ltd. has been listed on the US Federal Communications Commission

list of test facilities recognized to perform electromagnetic emissions measurements.

A2LA (Certificate Number: 3857.01)

TA Technology (Shanghai) Co., Ltd. has been listed by American Association for Laboratory

Accreditation to perform electromagnetic emission measurement.

1.3. Testing Location

Company:

TA Technology (Shanghai) Co., Ltd.

Address:

No.145, Jintang Rd, Tangzhen Industry Park, Pudong

City:

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2. General Description of Equipment under Test

Client Information

Applicant	Quectel Wireless Solutions Co., Ltd			
Applicant address	Building 5, Shanghai Business Park Phase III (Area B), No.1016			
Applicant address	Tianlin Road, Minhang District, Shanghai, China 200233			
Manufacturer	Quectel Wireless Solutions Co., Ltd			
Manufacturar address	Building 5, Shanghai Business Park Phase III (Area B), No.1016			
Manufacturer address	Tianlin Road, Minhang District, Shanghai, China 200233			

General information

EUT Description								
Model	BG95-M3							
IMEI	864475040001736	864475040001736						
Hardware Version	R2.1							
Software Version	BG95MR3LAR02A03							
Power Supply	External power supply	/						
	The EUT don't have	standard	Antenna,	The Antenna used				
Antenna Type	for testing in this repo	rt is the a	ıfter-market	t accessory (Dipole				
	Antenna)							
	GSM 1900:1.6dBi							
Antenna Gain	LTE Band 2:1.6dBi							
	LTE Band 25:1.7dBi							
Test Mode(s)	GSM1900; LTE Band	2/25;						
Test Modulation	(GSM)GMSK,8PSK; (LTE)QPS	SK,16QAM					
GPRS Multislot Class	33							
EGPRS Multislot Class	33							
LTE Category	M1							
	GSM 1900:		31.43dBm					
Maximum E.I.R.P	LTE Band 2:		22.52dBm					
	LTE Band 25:		22.21dBm					
Rated Power Supply Voltage	3.8V							
Extreme Voltage	Minimum: 3.3V Ma	ximum: 4	.3V					
Extreme Temperature	Lowest: -40°C Highest: +85°C							
	Band	Tx ((MHz)	Rx (MHz)				
Frequency Range(s)	GSM1900	1850	~ 1910	1930 ~ 1990				
r requericy Kange(s)	LTE Band 2	1850	~ 1910	1930 ~ 1990				
	LTE Band 25	1850	~ 1915	1930 ~ 1995				
Note: 1 The FLIT is sent from the applicant to TA and the information of the FLIT is declared by								

Note: 1. The EUT is sent from the applicant to TA and the information of the EUT is declared by the applicant.

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3. Applied Standards

According to the specifications of the manufacturer, it must comply with the requirements of the following standards:

Test standards:

FCC CFR 47 Part 24E (2019)

ANSI C63.26 (2015)

Reference standard:

FCC CFR47 Part 2 (2019)

KDB 971168 D01 Power Meas License Digital Systems v03r01





4. Test Configuration

Radiated measurements are performed by rotating the EUT in three different orthogonal test planes. EUT stand-up position (Z axis), lie-down position (X, Y axis). Receiver antenna polarization (horizontal and vertical), the worst emission was found in position (X axis, horizontal polarization) and the worst case was recorded.

All mode and data rates and positions and RB size and modulations were investigated.

Subsequently, only the worst case emissions are reported.

The following testing in GSM/ LTE is set based on the maximum RF Output Power.

Test modes are chosen to be reported as the worst case configuration below:

Test items	Modes/Modulation			
Test items	GSM 1900			
	GSM			
RF power output	GPRS			
	EGPRS			
	GSM			
Effective Isotropic Radiated power	GPRS(1Tx slot)			
	EGPRS(1Tx slot)			
	GSM			
Occupied Bandwidth	GPRS(1Tx slot)			
	EGPRS(1Tx slot)			
	GSM			
Band Edge Compliance	GPRS(1Tx slot)			
	EGPRS(1Tx slot)			
	GSM			
Peak-to-Average Power Ratio	GPRS(1Tx slot)			
	EGPRS(1Tx slot)			
	GSM			
Frequency Stability	GPRS(1Tx slot)			
	EGPRS(1Tx slot)			
Spurious Emissions at Antenna Terminals	GSM			
Radiates Spurious Emission	GSM			



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Test modes are chosen to be reported as the worst case configuration below for LTE Band 2/25:

Test items	Modes	Bandwidth (MHz)			Modulation		RB		Test Channel						
rest items	Wodes	1.4	3	5	10	15	20	QPSK	16QAM	1	50%	100%	L	M	н
RF power output	LTE 2	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Ni power output	LTE 25	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Effective Isotropic	LTE 2	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Radiated power	LTE 25	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Occupied	LTE 2	0	0	0	0	0	0	0	0	-	-	0	-	0	-
Bandwidth	LTE 25	0	0	0	0	0	0	0	0	-	-	0	-	0	-
Band Edge	LTE 2	0	0	0	0	0	0	0	0	0	-	0	0	1	0
Compliance	LTE 25	0	0	0	0	0	0	0	0	0	1	0	0	-	0
Peak-to-Average	LTE 2	Ο	0	0	Ο	Ο	0	0	0	-	-	0	-	0	-
Power Ratio	LTE 25	0	0	0	0	0	0	0	0	-	-	0	-	0	-
Frequency	LTE 2	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Stability	LTE 25	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Conducted	LTE 2	0	0	0	0	0	0	0	-	0	-	-	0	0	0
Spurious Emissions	LTE 25	0	0	0	0	0	0	0	-	0	-	-	0	0	0
Radiates	LTE 2	0	-	0	-	-	0	0	-	0	-	-	0	0	0
Spurious Emission	LTE 25	0	-	0	-	-	0	0	-	0	-	-	0	0	0
Note							-		chosen fo ot testing.		ting.				





5. Test Case Results

5.1.RF Power Output

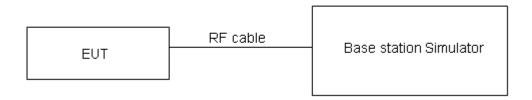
Ambient condition

Temperature Relative humidity		Pressure
23°C ~25°C	45%~50%	101.5kPa

Methods of Measurement

During the process of the testing, The EUT is controlled by the Base Station Simulator to ensure max power transmission and proper modulation.

Test Setup



The loss between RF output port of the EUT and the input port of the tester has been taken into consideration.

Limits

No specific RF power output requirements in part 2.1046.

Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for the normal distribution is with the coverage factor k = 2, U = 0.4 dB.

Test Results

		Conducted Power(dBm)				
GSM	1900	Channel 512	Channel 661	Channel 810		
		1850.2(MHz)	1880(MHz)	1909.8(MHz)		
GSM	Results	29.83	29.74	29.71		
	1TXslot	29.80	29.66	29.59		
GPRS/EGPRS	2TXslots	28.56	28.71	28.50		
(GMSK)	3TXslots	27.90	27.53	27.22		
	4TXslots	26.26	25.87	25.56		
	1TXslot	25.23	25.17	24.78		
EGPRS	2TXslots	24.20	24.04	24.01		
(8PSK)	3TXslots	22.45	22.01	21.94		
	4TXslots	21.23	21.02	20.74		

LTE Band 2	Channel/	Index	RB#	Conducted I	Power (dBm)
LIE Ballu Z	Frequency(MHz)	illuex	RBstart	QPSK	16QAM
	18607/1850.7	0	1#0	20.92	19.64
	10007/1000.7	0	6#0	18.71	19.02
1.4MHz	18900/1880	0	1#0	19.87	19.61
1.410172	10900/1000	0	6#0	18.38	18.19
	19193/1909.3	0	1#5	20.17	19.08
	19193/1909.3	0	6#0	18.35	18.68
	18615/1851.5	0	1#0	20.38	19.68
	10015/1051.5	0	6#0	18.78	18.91
3MHz	18900/1880	0	1#0	20.21	19.27
SIVITZ	16900/1660	0	6#0	18.45	18.73
	19185/1908.5	1	1#5	20.02	19.11
		1	6#0	18.41	18.74
	18625/1852.5	0	1#0	20.08	20.29
		0	6#0	19.47	19.66
5MHz	18900/1880	0	1#0	20.05	19.71
SIVIFIZ		0	6#0	19.24	19.38
	19175/1907.5	0	1#5	19.68	20.02
	19175/1907.5	3	6#0	19.28	19.40
	18650/1855	3	1#0	19.92	20.19
	10000/1000	0	4#0	20.07	19.83
10MHz	18900/1880	0	1#0	19.96	19.53
TUIVIE	10900/1000	0	4#0	19.78	20.11
	19150/1905	4	1#5	19.88	19.51
	19100/1900	7	4#2	20.01	20.14

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	40075/4057.5	3	1#0	20.22	20.11
	18675/1857.5	0	6#0	20.13	20.26
15MHz	18900/1880	0	1#0	20.14	19.81
ISIVIEZ	10900/1000	0	6#0	20.05	19.95
	19125/1902.5	8	1#5	19.95	19.51
	19125/1902.5	11	6#0	19.88	19.87
	18700/1860	3	1#0	20.17	19.96
		0	6#0	20.08	20.01
20MHz	18900/1880	0	1#0	19.90	19.59
ZUIVIFIZ		0	6#0	19.86	19.97
	10100/1000	12	1#5	19.76	19.34
	19100/1900	15	6#0	19.83	20.04

LTE Daniel OF	Channel/	la des	RB#	Conducted Power (dBm)			
LTE Band 25	Frequency(MHz)	Index	RBstart	QPSK	16QAM		
	20047/4050.7	0	1#0	20.51	19.47		
	26047/1850.7	0	6#0	18.36	18.71		
4 4 1 1 1 -	26265/4002 F	0	1#0	19.61	19.32		
1.4MHz	26365/1882.5	0	6#0	17.95	17.89		
	26683/1914.3	0	1#5	19.55	19.71		
	20083/1914.3	0	6#0	18.31	18.13		
	20055/4054 F	0	1#0	19.90	19.63		
	26055/1851.5	0	6#0	18.24	18.21		
3MHz	26265/4002 F	0	1#0	19.68	19.44		
SIVITZ	26365/1882.5	0	6#0	18.13	18.02		
	2007E/4042 E	1	1#5	19.72	19.58		
	26675/1913.5	1	6#0	18.21	18.19		
	26065/1852.5	0	1#0	19.89	20.03		
		0	6#0	19.31	19.45		
5MHz	26365/1882.5	0	1#0	19.67	19.96		
SIVIFIZ		0	6#0	19.13	19.21		
	26665/1912.5	0	1#5	19.66	19.88		
		3	6#0	19.33	19.48		
	26090/1855	3	1#0	19.78	19.93		
	20090/1000	0	4#0	19.79	19.63		
10MHz	26365/1882.5	0	1#0	19.68	19.98		
TOWINZ	20303/1002.3	0	4#0	19.67	19.47		
	26640/1910	4	1#5	19.64	19.94		
	20040/1910	7	4#2	19.78	19.52		
	26115/1857.5	3	1#0	19.88	19.97		
15MHz	20113/1037.3	0	6#0	19.81	19.91		
IJIVITIZ	26365/1882.5	0	1#0	19.71	19.98		
	20303/1002.3	0	6#0	19.75	19.84		



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	26615/1907.5	8	1#5	19.68	19.89
	20015/1907.5	11	6#0	19.78	19.89
	26140/1860	3	1#0	19.71	19.94
		0	6#0	19.87	19.93
20MHz	26365/1882.5	0	1#0	19.67	19.85
ZUIVITZ		0	6#0	19.76	19.84
	26590/1905	12	1#5	19.73	19.87
		15	6#0	19.81	19.93





5.2. Effective Isotropic Radiated Power

Ambient condition

Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Methods of Measurement

The testing follows FCC KDB 971168 v03r01 Section 5.8 and ANSI C63.26 (2015).

- a) Connect the equipment as illustrated. Mount the equipment with the manufacturer specified antenna in a vertical orientation on a manufacturer specified mounting surface located on a non-conducting rotating platform of a RF anechoic chamber (preferred) or a standard radiation site.
- b) Key the transmitter, then rotate the EUT 360° azimuthally and record spectrum analyzer power level (LVL) measurements at angular increments that are sufficiently small to permit resolution of all peaks. If a standard radiation test site is used, raise and lower the test antenna to obtain a maximum reading at each angular increment. (Note: several batteries may be needed to offset the effect of battery voltage droop, which should not exceed 5% of the manufactured specified battery voltage during transmission).
- c) Replace the transmitter under test with a vertically polarized half-wave dipole (or an antenna whose gain is known relative to an ideal half-wave dipole). The center of the antenna should be at the same location as the center of the antenna under test.
- d) Connect the antenna to a signal generator with a known output power and record the path loss (in dB) as LOSS. If a standard radiation test site is used, raise and lower the test antenna to obtain a maximum reading.LOSS = Generator Output Power (dBm) - Analyzer reading (dBm)
- e) Determine the effective radiated output power at each angular position from the readings in steps b) and d) using the following equation: ERP (dBm) = LVL (dBm) + LOSS (dB)
- f) The maximum ERP is the maximum value determined in the preceding step.
- When calculating ERP, in addition to knowing the antenna radiation and matching characteristics, it is necessary to know the loss values of all elements (e.g. transmission line attenuation, mismatches, filters, combiners) interposed between the point where transmitter output power is measured, and the point where power is applied to the antenna. ERP can then be calculated as follows:

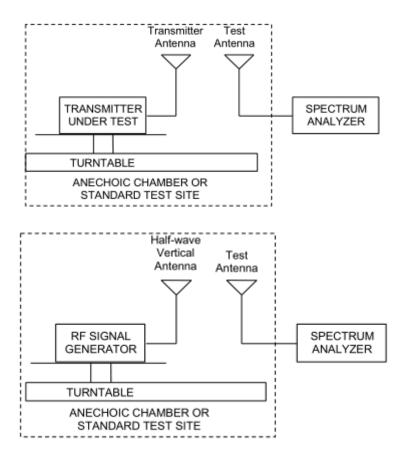
EIRP (dBm) = Output Power (dBm) - Losses (dB) + Antenna Gain (dBi) where:dBd refers to gain relative to an ideal dipole.

EIRP (dBm) = ERP (dBm) + 2.15 (dB.)

The RB allocation refers to section 5.1, using the maximum output power configuration.



Test setup



Limits

Rule Part 24.232(c) Mobile and portable stations are limited to 2 watts EIRP.

Rule Part 24.232(e) Peak transmit power must be measured over any interval of continuous transmission using instrumentation calibrated in terms of an rms-equivalent voltage.



Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for the normal distribution is with the coverage factor k = 2, U = 1.19 dB



Test Results:

The measurement is performed for both of horizontal and vertical antenna Polarization, and only the data of worst mode is recorded in this report.

Mode	Channel	Frequency (MHz)	Polarization	EIRP (dBm)	Limit (dBm)	Conclusion
CCM	Low	1850.2	Horizontal	31.43	33	Pass
GSM 1900	Mid	1880	Horizontal	31.34	33	Pass
1900	High	1909.8	Horizontal	31.31	33	Pass
CDDC	Low	1850.2	Horizontal	31.40	33	Pass
GPRS 1900	Mid	1880	Horizontal	31.26	33	Pass
1900	High	1909.8	Horizontal	31.19	33	Pass
EGPRS	Low	1850.2	Horizontal	26.83	33	Pass
1900	Mid	1880	Horizontal	26.77	33	Pass
1900	High	1909.8	Horizontal	26.38	33	Pass

	LTE Band 2						
Band2	Channel/	Index	RB#	EIRP	(dBm)	Limit	Conclusion
Dariuz	Frequency(MHz)	ilidex	RBstart	QPSK	16QAM	(dBm)	Conclusion
	18607/1850.7	0	1#0	22.52	21.24	33	Pass
	18007/1830.7	0	6#0	20.31	20.62	33	Pass
1.4MHz	18900/1880	0	1#0	21.47	21.21	33	Pass
I.4IVI⊓Z	10900/1000	0	6#0	19.98	19.79	33	Pass
	19193/1909.3	0	1#5	21.77	20.68	33	Pass
	19193/1909.3	0	6#0	19.95	20.28	33	Pass
	18615/1851.5	0	1#0	21.98	21.28	33	Pass
	10015/1051.5	0	6#0	20.38	20.51	33	Pass
3MHz	18900/1880	0	1#0	21.81	20.87	33	Pass
SIVITZ	10900/1000	0	6#0	20.05	20.33	33	Pass
	19185/1908.5	1	1#5	21.62	20.71	33	Pass
	19165/1906.5	1	6#0	20.01	20.34	33	Pass
	18625/1852.5	0	1#0	21.68	21.89	33	Pass
	10023/1032.3	0	6#0	21.07	21.26	33	Pass
5MHz	18900/1880	0	1#0	21.65	21.31	33	Pass
SIVITZ	10900/1000	0	6#0	20.84	20.98	33	Pass
	19175/1907.5	0	1#5	21.28	21.62	33	Pass
	19175/1907.5	3	6#0	20.88	21.00	33	Pass
	18650/1855	3	1#0	21.52	21.79	33	Pass
10MHz	10030/1033	0	4#0	21.67	21.43	33	Pass
TUIVITZ	18900/1880	0	1#0	21.56	21.13	33	Pass
	16900/1660	0	4#0	21.38	21.71	33	Pass

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	19150/1905	4	1#5	21.48	21.11	33	Pass
	19150/1905	7	4#2	21.61	21.74	33	Pass
	18675/1857.5	3	1#0	21.82	21.71	33	Pass
	10075/1057.5	0	6#0	21.73	21.86	33	Pass
15MHz	18900/1880	0	1#0	21.74	21.41	33	Pass
TOWINZ	10900/1000	0	6#0	21.65	21.55	33	Pass
	19125/1902.5	8	1#5	21.55	21.11	33	Pass
	19125/1902.5	11	6#0	21.48	21.47	33	Pass
	18700/1860	3	1#0	21.77	21.56	33	Pass
	16700/1660	0	6#0	21.68	21.61	33	Pass
20MHz	18900/1880	0	1#0	21.50	21.19	33	Pass
ZUIVITZ	10900/1000	0	6#0	21.46	21.57	33	Pass
	19100/1900	12	1#5	21.36	20.94	33	Pass
	19100/1900	15	6#0	21.43	21.64	33	Pass

			LTE Ban	d 25			
Band2	Channel/	Index	RB#	EIRP	(dBm)	Limit	Conclusion
Dariuz	Frequency(MHz)	index	RBstart	QPSK	16QAM	(dBm)	Conclusion
	26047/1850.7	0	1#0	22.21	21.17	33	Pass
	20047/1000.7	0	6#0	20.06	20.41	33	Pass
1.4MHz	26365/1882.5	0	1#0	21.31	21.02	33	Pass
1.41111112	20303/1002.3	0	6#0	19.65	19.59	33	Pass
	26683/1914.3	0	1#5	21.25	21.41	33	Pass
	20003/1914.3	0	6#0	20.01	19.83	33	Pass
	26055/1851.5	0	1#0	21.60	21.33	33	Pass
	20055/1651.5	0	6#0	19.94	19.91	33	Pass
3MHz	26365/1882.5	0	1#0	21.38	21.14	33	Pass
SIVITIZ	20303/1002.3	0	6#0	19.83	19.72	33	Pass
	26675/1913.5	1	1#5	21.42	21.28	33	Pass
	20073/1913.3	1	6#0	19.91	19.89	33	Pass
	26065/1852.5	0	1#0	21.59	21.73	33	Pass
	20003/1032.3	0	6#0	21.01	21.15	33	Pass
5MHz	26365/1882.5	0	1#0	21.37	21.66	33	Pass
SIVITIZ	20303/1002.3	0	6#0	20.83	20.91	33	Pass
	26665/1912.5	0	1#5	21.36	21.58	33	Pass
	20005/1912.5	3	6#0	21.03	21.18	33	Pass
	26090/1855	3	1#0	21.48	21.63	33	Pass
	20090/1000	0	4#0	21.49	21.33	33	Pass
10MHz	26365/1882.5	0	1#0	21.38	21.68	33	Pass
	20300/1002.0	0	4#0	21.37	21.17	33	Pass
	26640/1910	4	1#5	21.34	21.64	33	Pass



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		7	4#2	21.48	21.22	33	Pass
	26115/1857.5	3	1#0	21.58	21.67	33	Pass
	20115/1657.5	0	6#0	21.51	21.61	33	Pass
15MHz	26365/1882.5	0	1#0	21.41	21.68	33	Pass
TOMITZ	20303/1002.3	0	6#0	21.45	21.54	33	Pass
	26615/1907.5	8	1#5	21.38	21.59	33	Pass
	20013/1907.3	11	6#0	21.48	21.59	33	Pass
	26140/1860	3	1#0	21.41	21.64	33	Pass
	20140/1000	0	6#0	21.57	21.63	33	Pass
20MHz	26365/1882.5	0	1#0	21.37	21.55	33	Pass
ZUIVITZ	20303/1002.3	0	6#0	21.46	21.54	33	Pass
	26590/1905	12	1#5	21.43	21.57	33	Pass
	20390/1903	15	6#0	21.51	21.63	33	Pass

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5.3. Occupied Bandwidth

Ambient condition

Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Method of Measurement

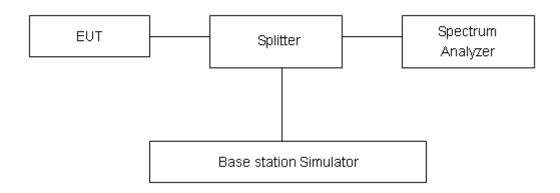
The EUT was connected to Spectrum Analyzer and Base Station Simulator via power Splitter. The occupied bandwidth is measured using spectrum analyzer.

RBW is set to 3kHz, VBW is set to 10kHz for GSM 1900,

RBW is set to 51kHz, VBW is set to 160kHz for LTE Band 2/25

99% power and -26dBc occupied bandwidths are recorded. Spectrum analyzer plots are included on the following pages.

Test Setup



Limits

No specific occupied bandwidth requirements in part 2.1049.

Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for the normal distribution is with the coverage factor k = 2, U = 624Hz.



Test Result

Mode	Channel	Frequency (MHz)	99% Power Bandwidth (MHz)	-26dBc Bandwidth(MHz)
	512	1850.2	0.24588	0.2997
GSM 1900 (GMSK)	661	1880.0	0.24074	0.2996
(Gillort)	810	1909.8	0.24657	0.3002
	512	1850.2	0.24343	0.3139
GPRS 1900 (GMSK)	661	1880.0	0.24206	0.305
(GMOR)	810	1909.8	0.24476	0.3112
	512	1850.2	0.24864	0.3152
EGPRS 1900 (8-PSK)	661	1880.0	0.24666	0.3106
(5 : 511)	810	1909.8	0.24646	0.3178

			Channel/			Bandwid	lth(MHz)
Mode	Bandwidth	Modulation		RB	Index	99%	-26dBc
			Frequency(MHz)			Power	-200BC
	1.4MHz	QPSK	18900/1880	6#0	0	1.1068	1.361
	1.4101712	16QAM	18900/1880	6#0	0	0.9417	1.167
	3MHz	QPSK	18900/1880	6#0	0	1.1172	1.453
	SIVIFIZ	16QAM	18900/1880	6#0	0	0.9577	1.432
	5MHz	QPSK	18900/1880	6#0	0	1.1239	1.363
Band2	SIVITZ	16QAM	18900/1880	6#0	0	0.9488	1.183
Danuz	10MHz	QPSK	18900/1880	6#0	0	1.1139	1.325
	TUIVITZ	16QAM	18900/1880	6#0	0	0.9723	1.212
	15MHz	QPSK	18900/1880	6#0	0	1.1262	1.349
	TOWITZ	16QAM	18900/1880	6#0	0	0.9697	1.253
	20MHz	QPSK	18900/1880	6#0	0	1.1323	1.355
	ΖυΙνίΠΖ	16QAM	18900/1880	6#0	0	0.965	1.247

			Channel		Channel/ Bandwidth(MHz		Ith(MHz)
Mode	Bandwidth	Modulation	Channel/	RB	Index	99%	-26dBc
			Frequency(MHz)			Power	-20ubc
	1.4MHz	QPSK	26365/1882.5	6#0	0	1.1056	1.359
Band25	1.410172	16QAM	26365/1882.5	6#0	0	0.9446	1.162
Dailu23	2MH-	QPSK	26365/1882.5	6#0	0	1.1135	1.327
	3MHz	16QAM	26365/1882.5	6#0	0	0.9518	1.172

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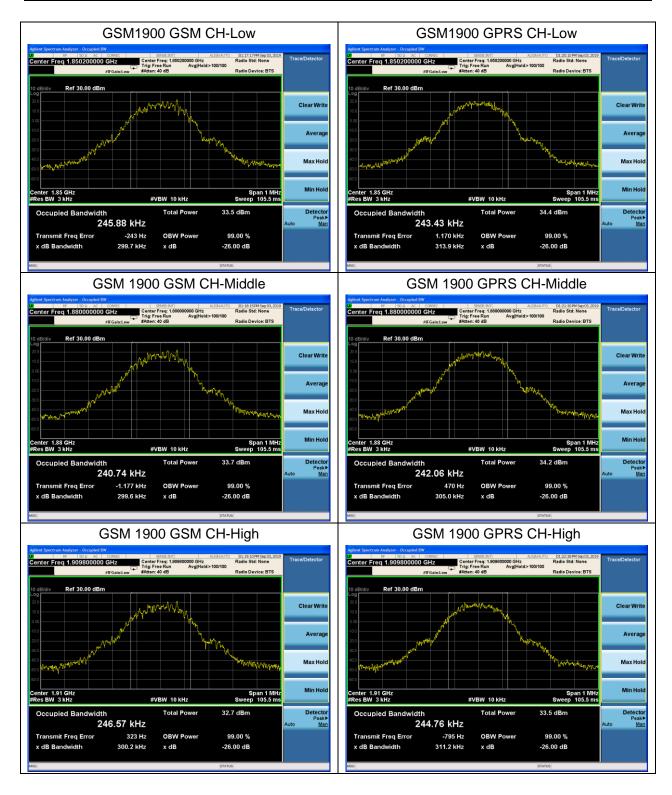


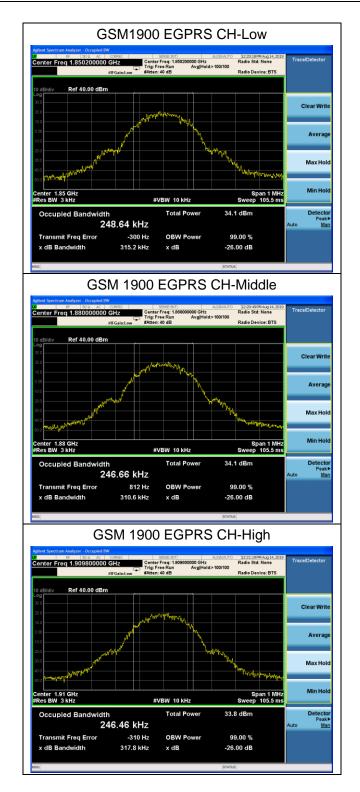
RF Test Report Report No.: R2003A0152-R2

5MU-	QPSK	26365/1882.5	6#0	0	1.1132	1.33
SIVIFIZ	16QAM	26365/1882.5	6#0	0	0.9514	1.1216
10MHz	QPSK	26365/1882.5	6#0	0	1.1223	1.334
TOWINZ	16QAM	26365/1882.5	6#0	0	0.966	1.222
1511117	QPSK	26365/1882.5	6#0	0	1.1283	1.375
TOIVITZ	16QAM	26365/1882.5	6#0	0	0.9671	1.243
201411-	QPSK	26365/1882.5	6#0	0	1.124	1.369
ZUIVITZ	16QAM	26365/1882.5	6#0	0	0.9653	1.255
	5MHz 10MHz 15MHz 20MHz	16QAM 10MHz 16QAM 16QAM 15MHz QPSK 16QAM 16QAM QPSK 16QAM QPSK	5MHz 16QAM 26365/1882.5 10MHz QPSK 26365/1882.5 16QAM 26365/1882.5 15MHz QPSK 26365/1882.5 16QAM 26365/1882.5 16QAM 26365/1882.5 QPSK 26365/1882.5	5MHz 16QAM 26365/1882.5 6#0 10MHz QPSK 26365/1882.5 6#0 16QAM 26365/1882.5 6#0 15MHz QPSK 26365/1882.5 6#0 16QAM 26365/1882.5 6#0 QPSK 26365/1882.5 6#0 QPSK 26365/1882.5 6#0	5MHz 16QAM 26365/1882.5 6#0 0 10MHz QPSK 26365/1882.5 6#0 0 16QAM 26365/1882.5 6#0 0 15MHz QPSK 26365/1882.5 6#0 0 16QAM 26365/1882.5 6#0 0 20MHz QPSK 26365/1882.5 6#0 0	5MHz 16QAM 26365/1882.5 6#0 0 0.9514 10MHz QPSK 26365/1882.5 6#0 0 1.1223 16QAM 26365/1882.5 6#0 0 0.966 15MHz QPSK 26365/1882.5 6#0 0 1.1283 16QAM 26365/1882.5 6#0 0 0.9671 20MHz QPSK 26365/1882.5 6#0 0 1.124



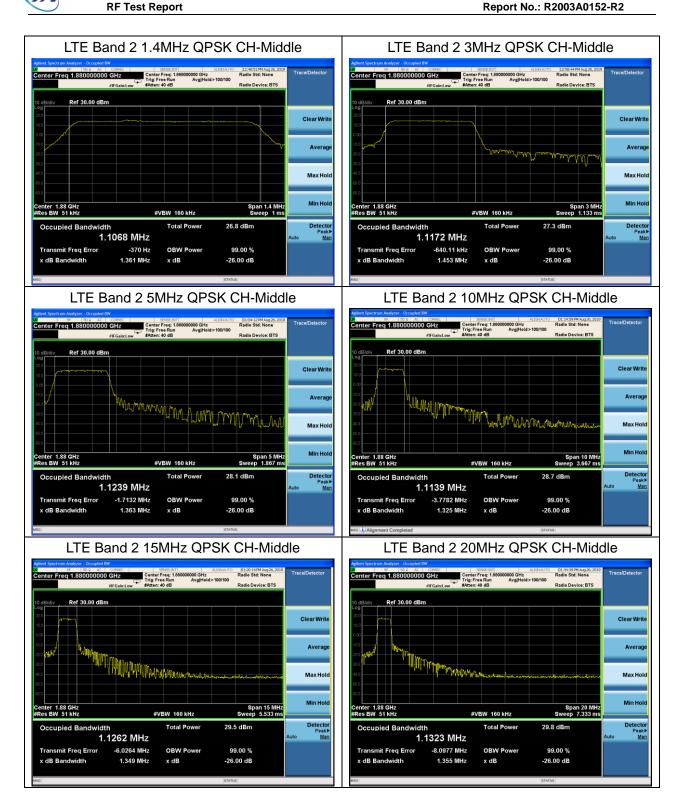






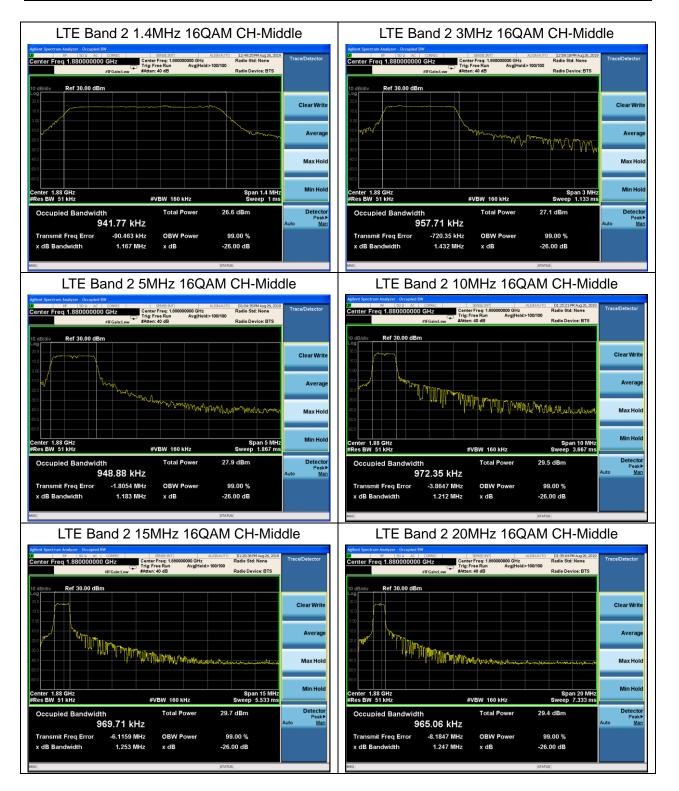






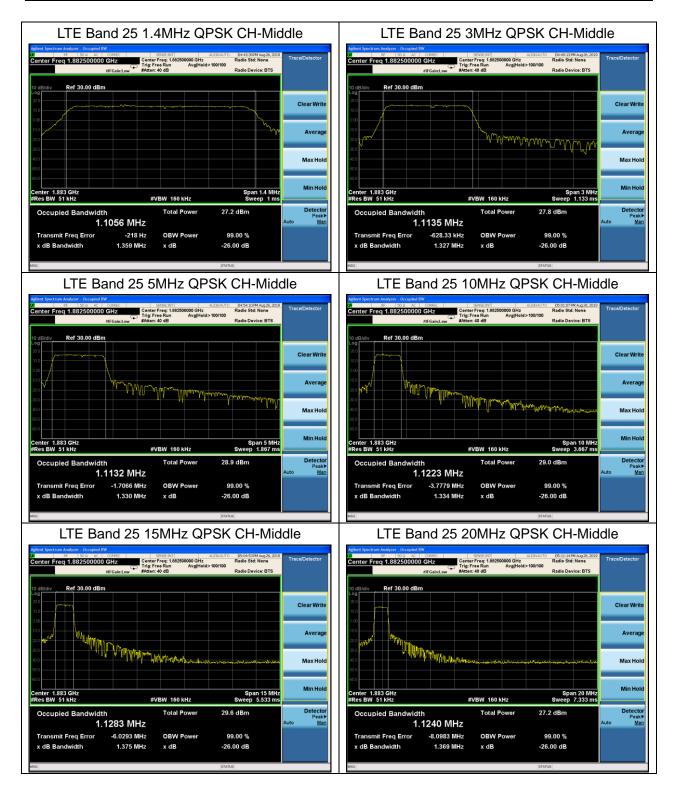






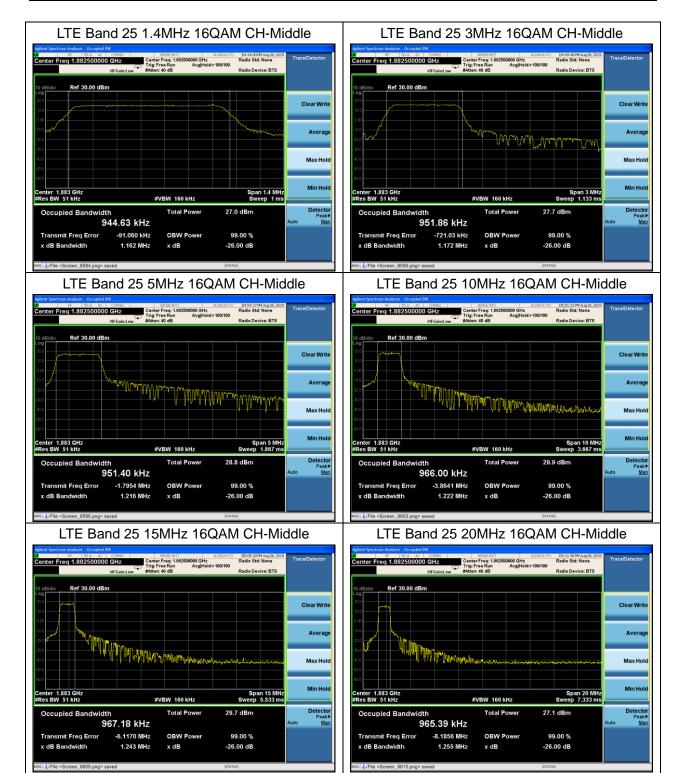
















5.4. Band Edge Compliance

Ambient condition

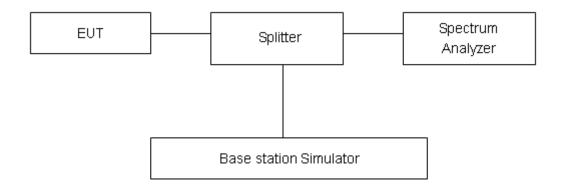
Temperature	Relative humidity	Pressure
23°C ~25°C	45%~50%	101.5kPa

Method of Measurement

The EUT was connected to Spectrum Analyzer and Base Station Simulator via power Splitter. The band edge of the lowest and highest channels were measured. The Average detector is used and RBW is set to 3kHz, VBW is set to 10kHz for GSM 1900,

RBW is set to 51kHz, VBW is set to 160kHz for LTE Band 2/25 Spectrum analyzer plots are included on the following pages.

Test Setup



Limits

Rule Part 24.238(a) specifies that "on any frequency outside a licensee's frequency block, the power of any emission shall be attenuated below the transmitter power (P) by at least 43 + 10 log10 (P) dB."

Limit	-13 dBm
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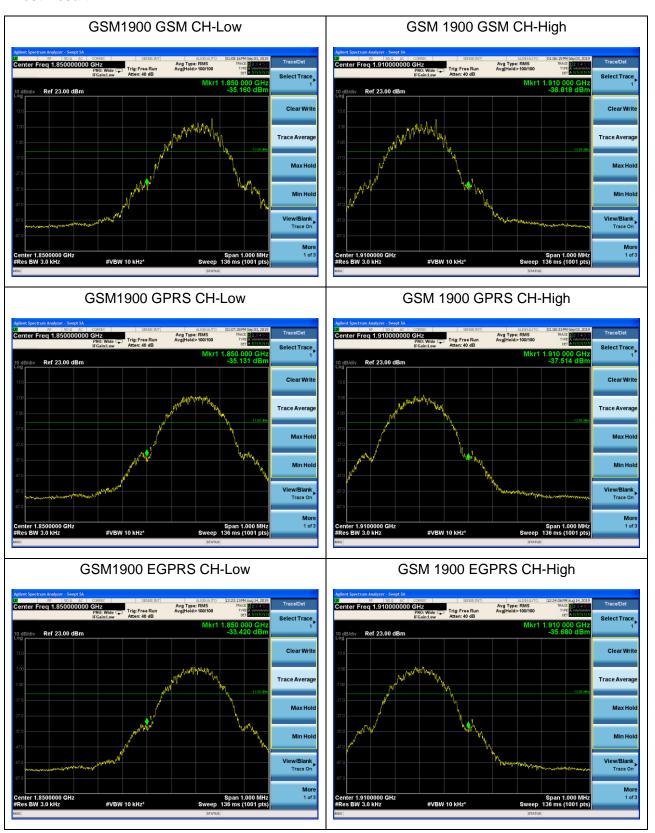
Measurement Uncertainty

The assessed measurement uncertainty to ensure 95% confidence level for the normal distribution is with the coverage factor k = 1.96, U = 0.684dB.





Test Result:



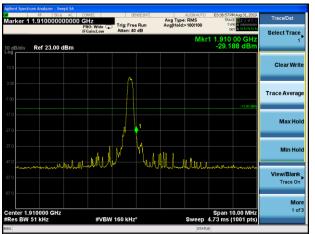




LTE Band 2 1.4MHz QPSK 1RB CH-Low



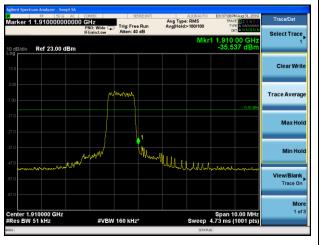
LTE Band 2 1.4MHz QPSK 1RB CH-High



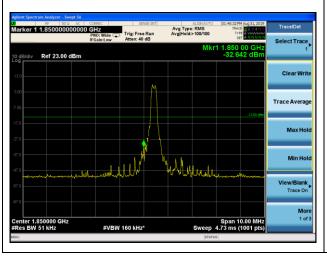
LTE Band 2 1.4MHz QPSK 100%RB CH-Low



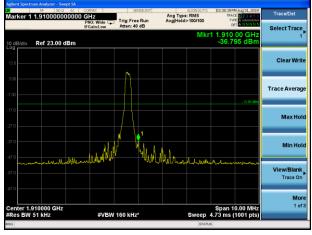
LTE Band 2 1.4MHz QPSK 100%RB CH-High



LTE Band 2 3MHz QPSK 1RB CH-Low

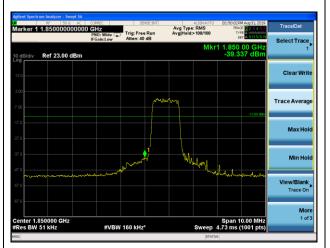


LTE Band 2 3MHz QPSK 1RB CH-High





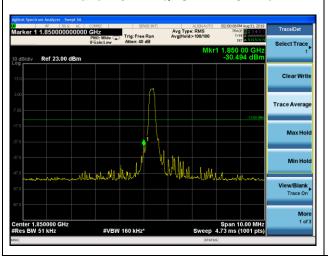
LTE Band 2 3MHz QPSK 100%RB CH-Low



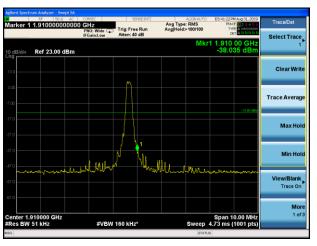
LTE Band 2 3MHz QPSK 100%RB CH-High



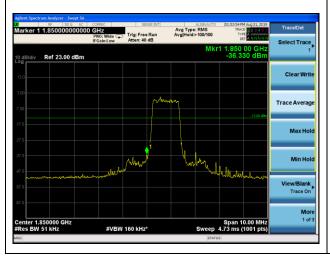
LTE Band 2 5MHz QPSK 1RB CH-Low



LTE Band 2 5MHz QPSK 1RB CH-High



LTE Band 2 5MHz QPSK 100%RB CH-Low

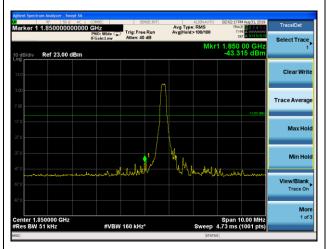


LTE Band 2 5MHz QPSK 100%RB CH-High





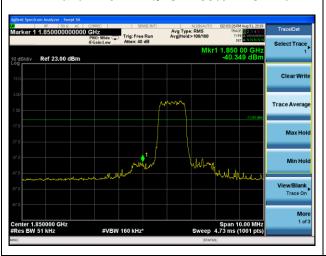
LTE Band 2 10MHz QPSK 1RB CH-Low



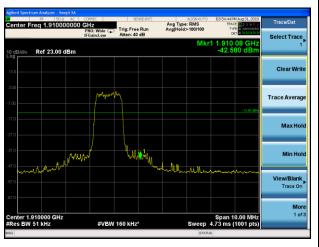
LTE Band 2 10MHz QPSK 1RB CH-High



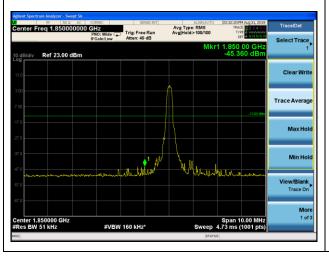
LTE Band 2 10MHz QPSK 100%RB CH-Low



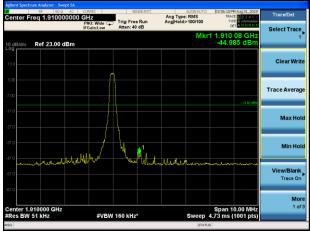
LTE Band 2 10MHz QPSK 100%RB CH-High



LTE Band 2 15MHz QPSK 1RB CH-Low



LTE Band 2 15MHz QPSK 1RB CH-High





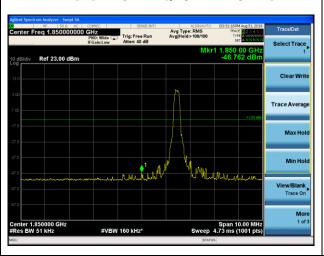
LTE Band 2 15MHz QPSK 100%RB CH-Low



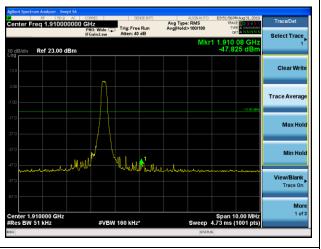
LTE Band 2 15MHz QPSK 100%RB CH-High



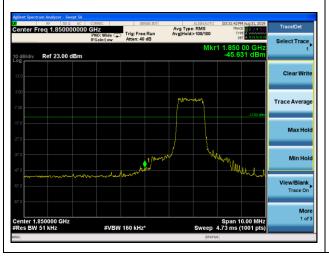
LTE Band 2 20MHz QPSK 1RB CH-Low



LTE Band 2 20MHz QPSK 1RB CH-High



LTE Band 2 20MHz QPSK 100%RB CH-Low



LTE Band 2 20MHz QPSK 100%RB CH-High

